Form PTO-1449			ATTY DOCKET NO. 1768-000001/US		APPLICATION NO.		
INFORMATION DISCLOSURE CITATION IN AN APPLICATION (Use several sheets if necessary)			APPLICANT Tsuyoshi ONO, et al.		CONF. NO. Unknown		
			FILING DATE January 21, 2004		GROUP Unknown		
<u></u>		U.S. PATENT DO	CUMENTS		<u></u>		
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th	Giovanni Campardo, et al., "40-mm2 3-V-Only 50-MHz 64-Mb 2-v/Cell CHE NOR Flash Memory", IEEE Journal Of Solid-State Circuits, Vol. 35, No. 11, November 2000						
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EXAMINER HIEN NGUYEN DATE CONSIDERED 4/1/05							
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